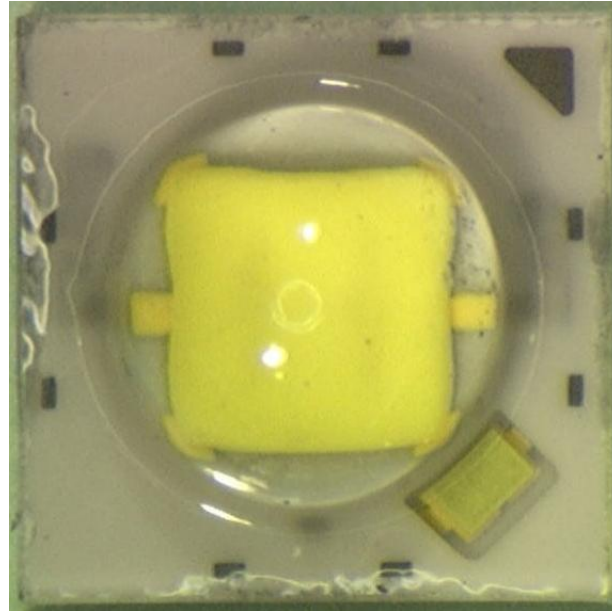


Reverse Costing analysis



Nichia NCSW119T

September 2010 - Version 3
Written by: Sylvain HALLEREAU

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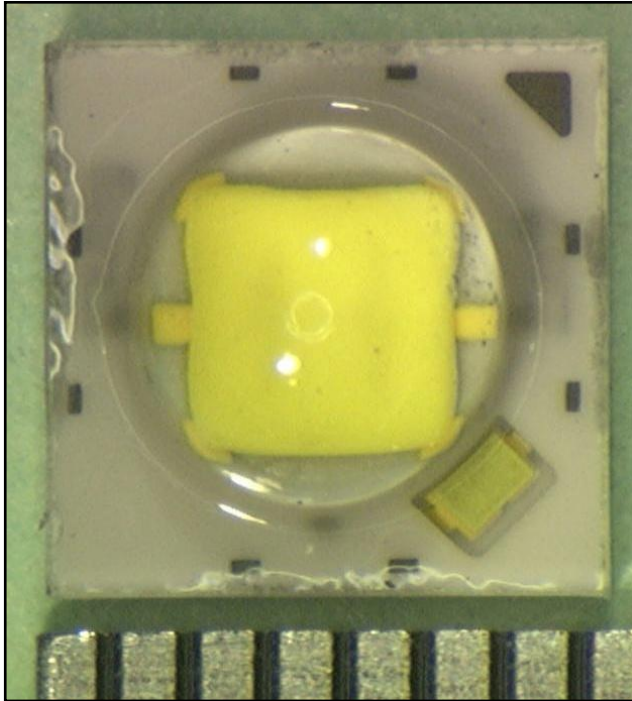
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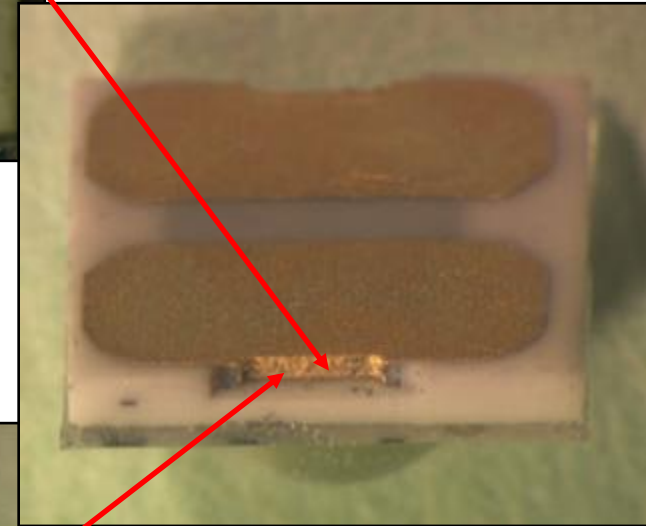
Conclusion76

Version 2 : 2 slides have been add on the active layers.

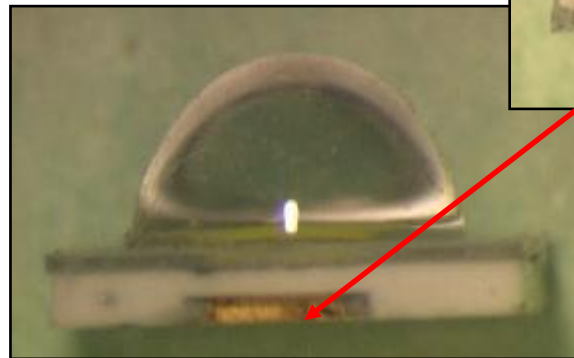
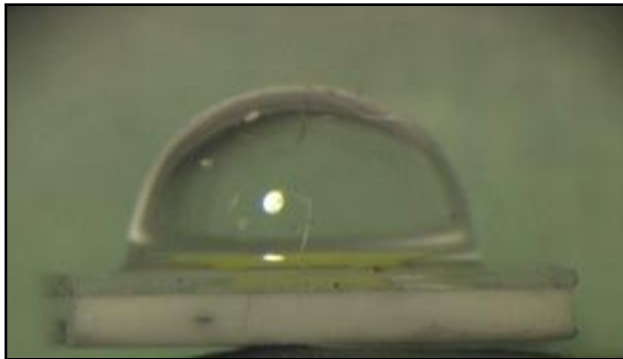
Version 3 : the package cost has been modified with a phosphor cost at \$0.0015.



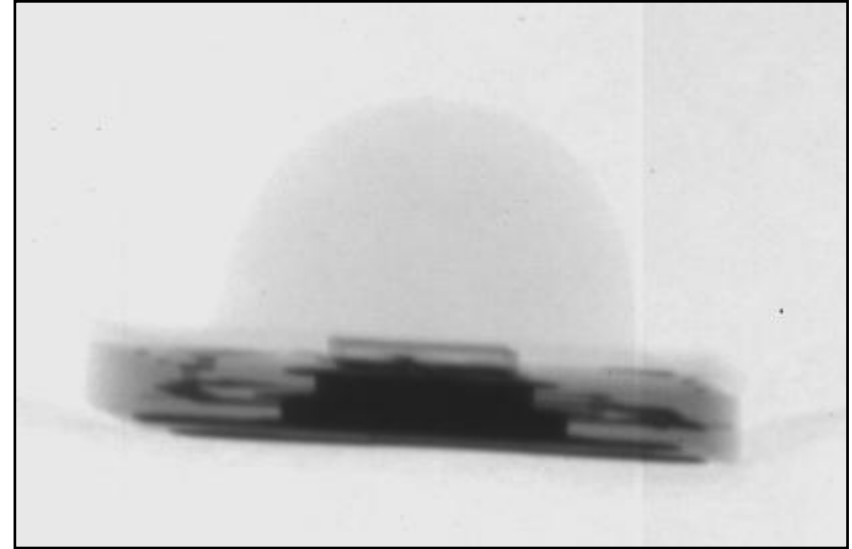
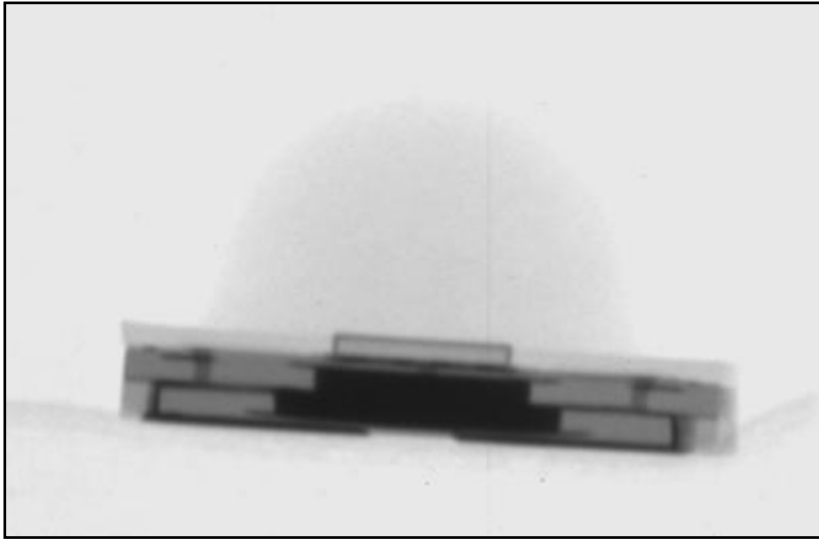
Underside view of the NCSW119T.



Top view of the NCSW119T. The NCSW119T package is 3.5x3.5mm in dimension.

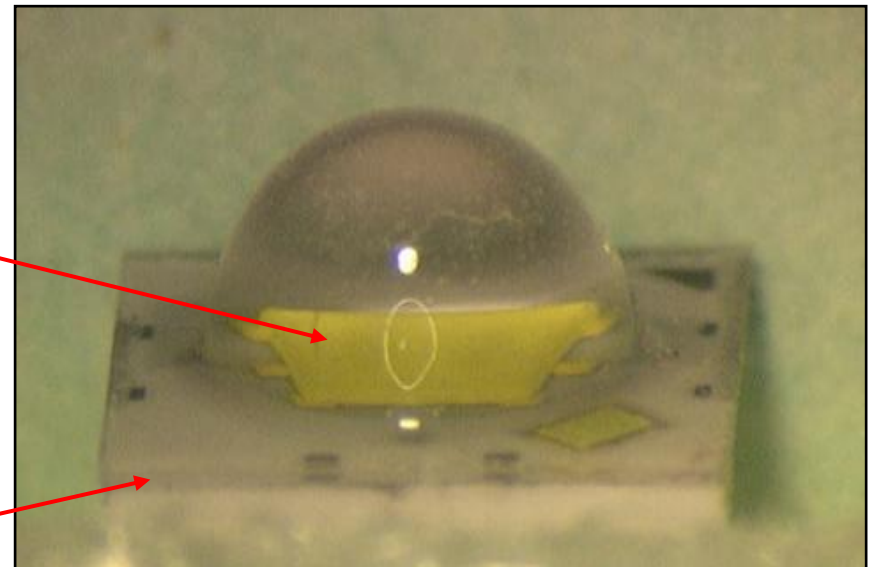


Elevation views of the NCSW119T LED. The ceramic substrate is 450um thick.



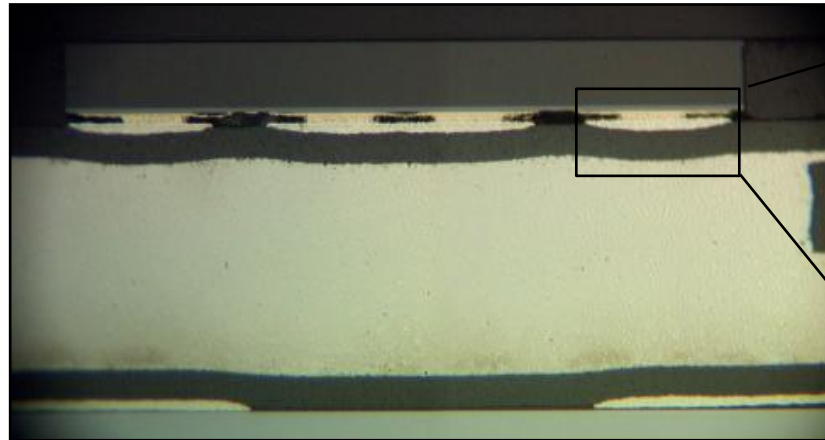
Elevation view XRAYs, in the X and Y directions and at different contrasts.

The fluorescent medium.
Only the LED is coated.

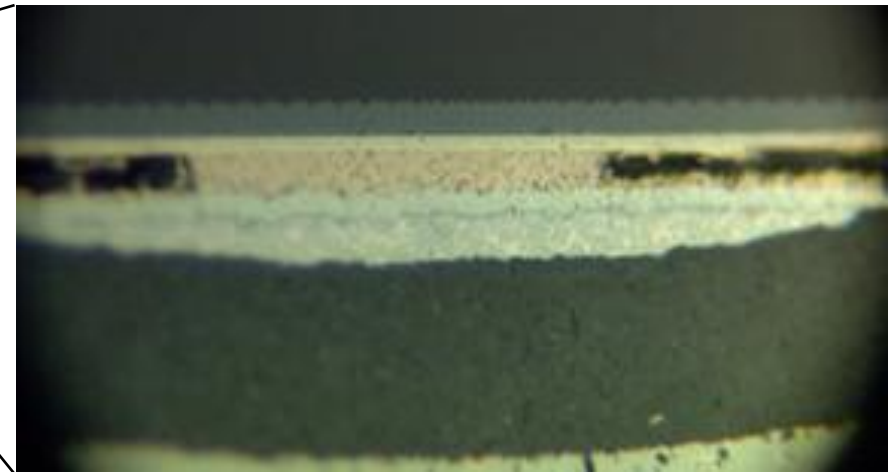


The lens is overmolded on the ceramic package.

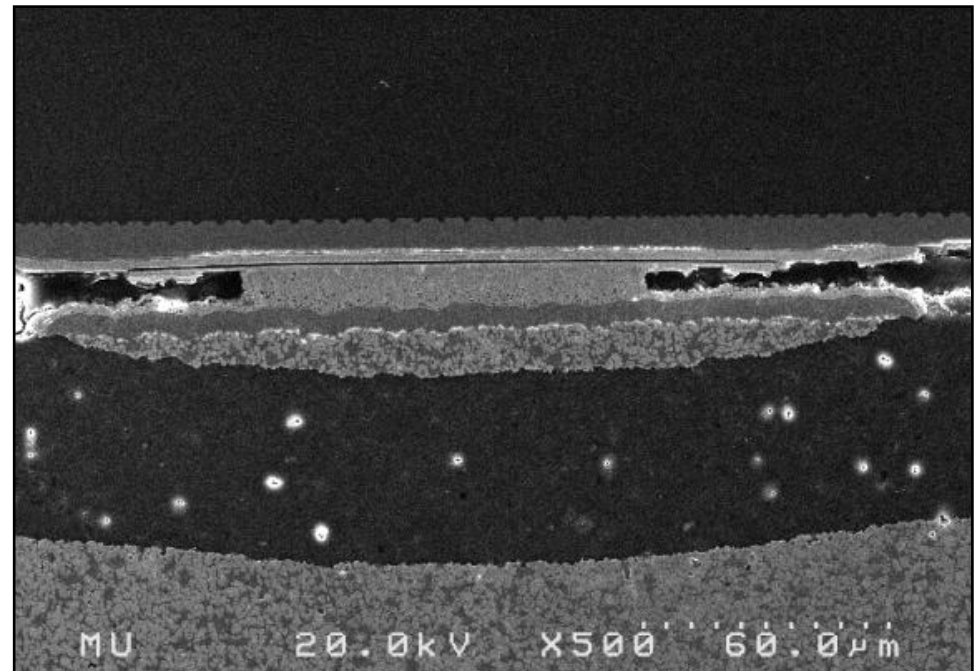
Angle view



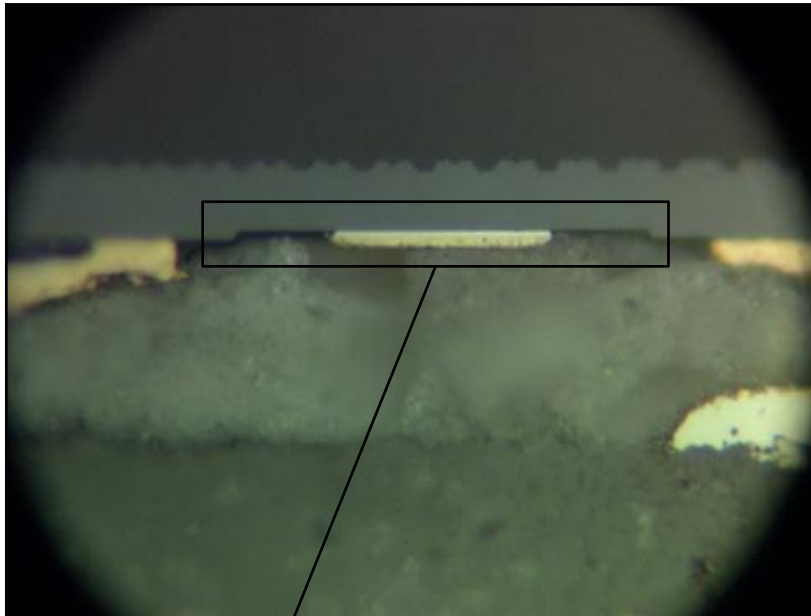
View of the bumps with through-the-lens illumination.



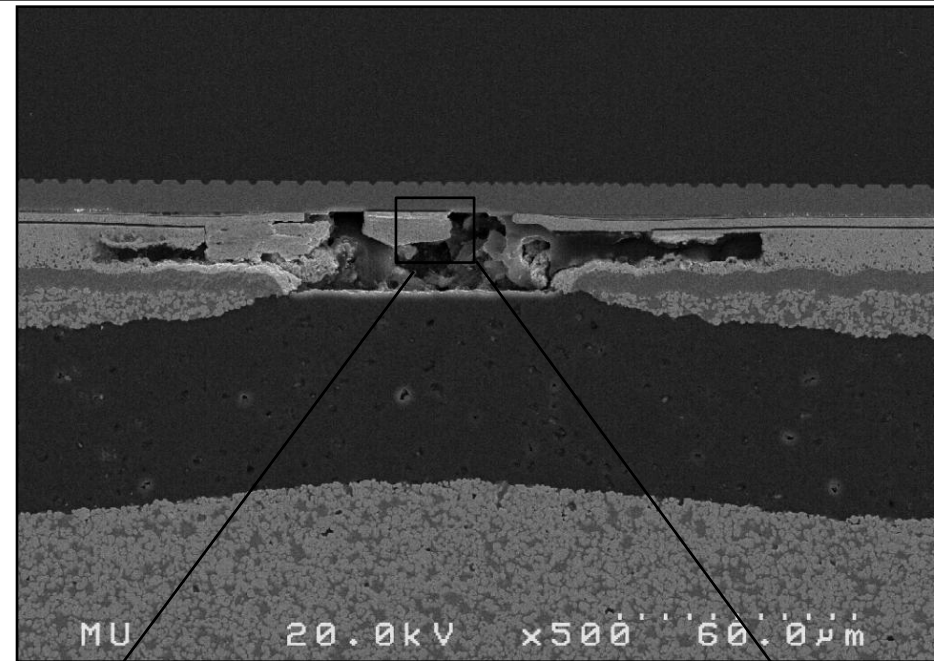
Optical and SEM close-ups of bumps.



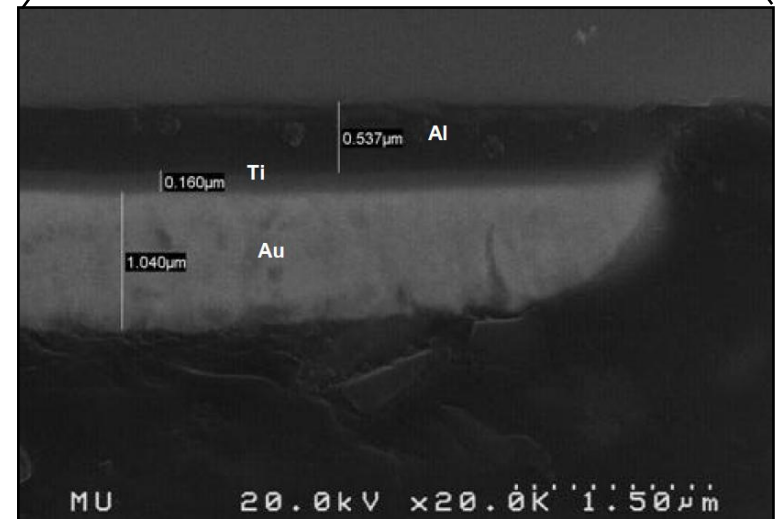
Optical image of boxed region. This is the cathode die contact.



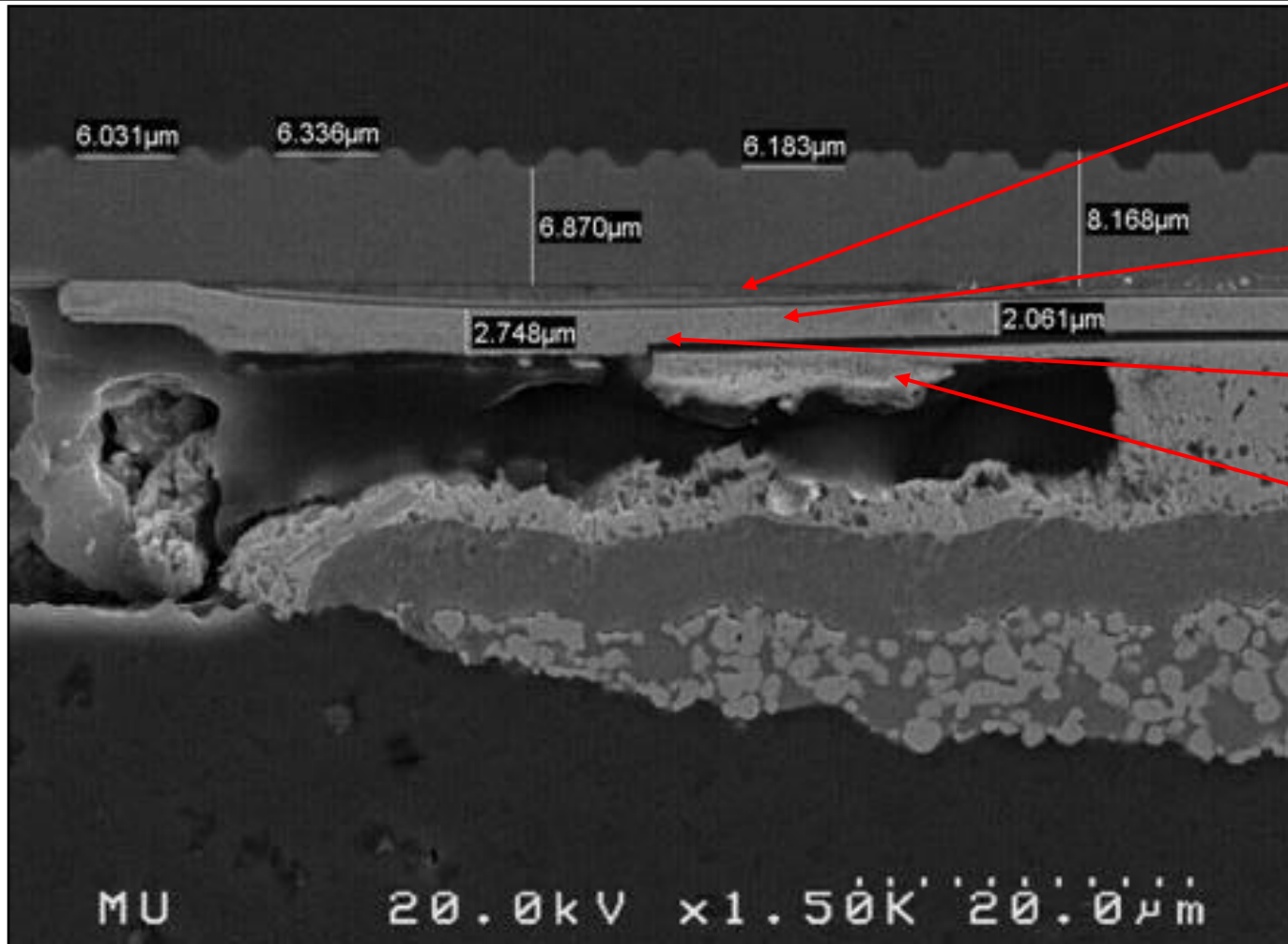
The GaN layer is etched for allow the contact with the N layer.



SEM image of boxed region.



Metallurgy of the contact



The Ag and Au-Ti-Ti layers are deposited by shadow masking.

A thick gold layer is deposited and patterned.

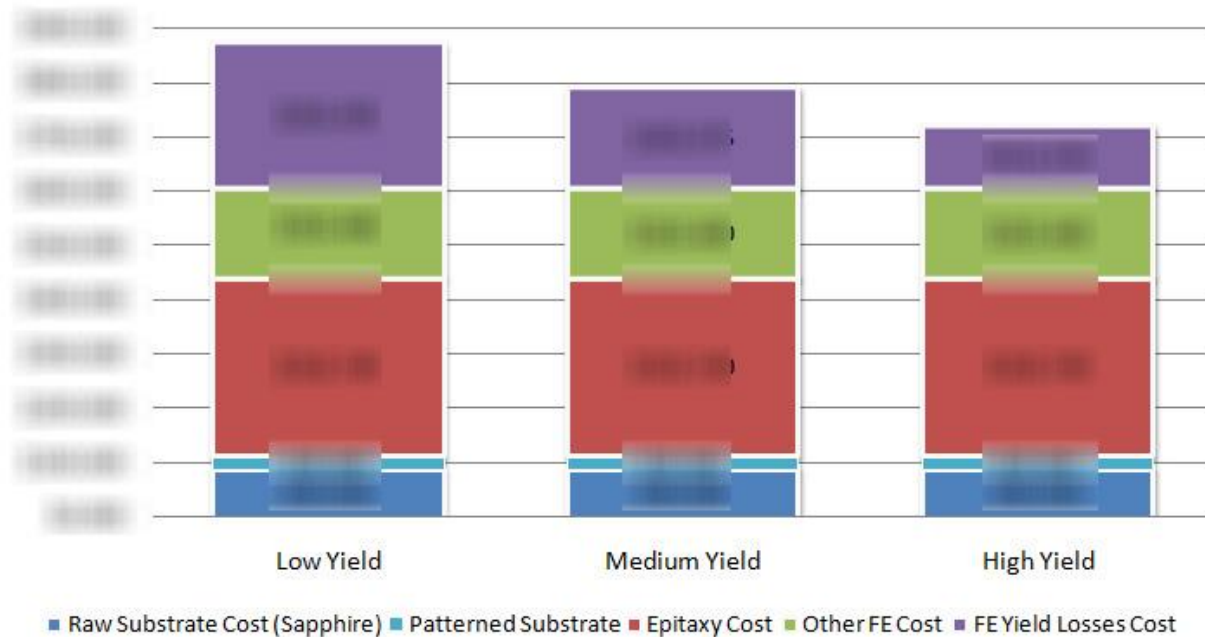
A thin recess is realized in the gold layer.

The W, Al, TiW and 0.Xµm of gold are deposited by shadow masking.

SEM cross section view : anode electrode with the bump between the LED and the ceramic package.

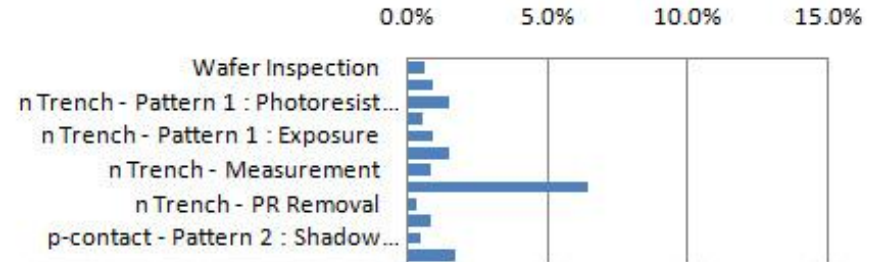
| Total Front-End | Low Yield | | Medium Yield | | High Yield | |
|-------------------------------|-----------|-----------|--------------|-----------|------------|-----------|
| | Cost | Breakdown | Cost | Breakdown | Cost | Breakdown |
| Raw Substrate Cost (Sapphire) | | | | | | |
| Patterned Substrate | | | | | | |
| Epitaxy Cost | | | | | | |
| Other FE Cost | | | | | | |
| FE Yield Losses Cost | | | | | | |
| TOTAL Front-End Cost | | | | | | |

Front-End Cost Breakdown



•Details of the equipment cost per step are given in the Excel Spreadsheet.

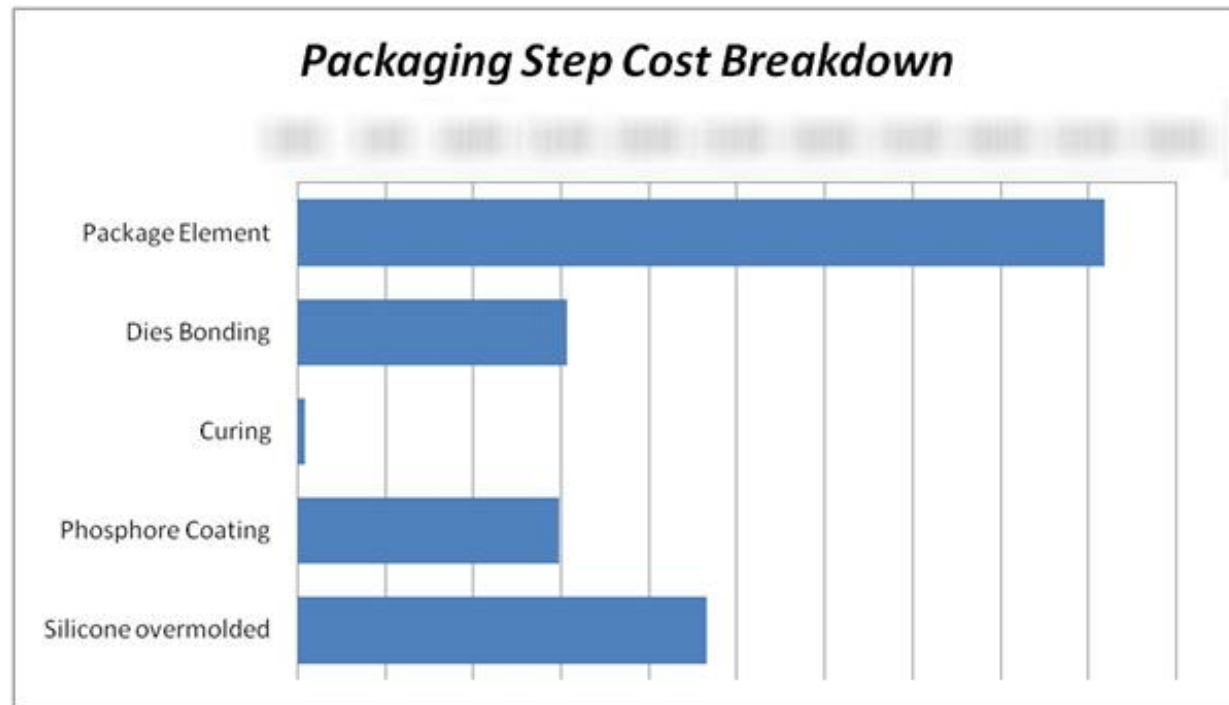
Other FE Step Cost Breakdown



| Other FE Steps | Cost | Breakdown |
|--|------|-----------|
| Wafer Inspection | | |
| Wafer Cleaning | | |
| n Trench - Pattern 1 : Photoresist Coating | | |
| n Trench - Pattern 1 : Baking | | |
| n Trench - Pattern 1 : Exposure | | |
| n Trench - Pattern 1 : Development | | |
| n Trench - Measurement | | |
| n Trench - Dry Etching (1.4µm) | | |
| n Trench - PR Removal | | |

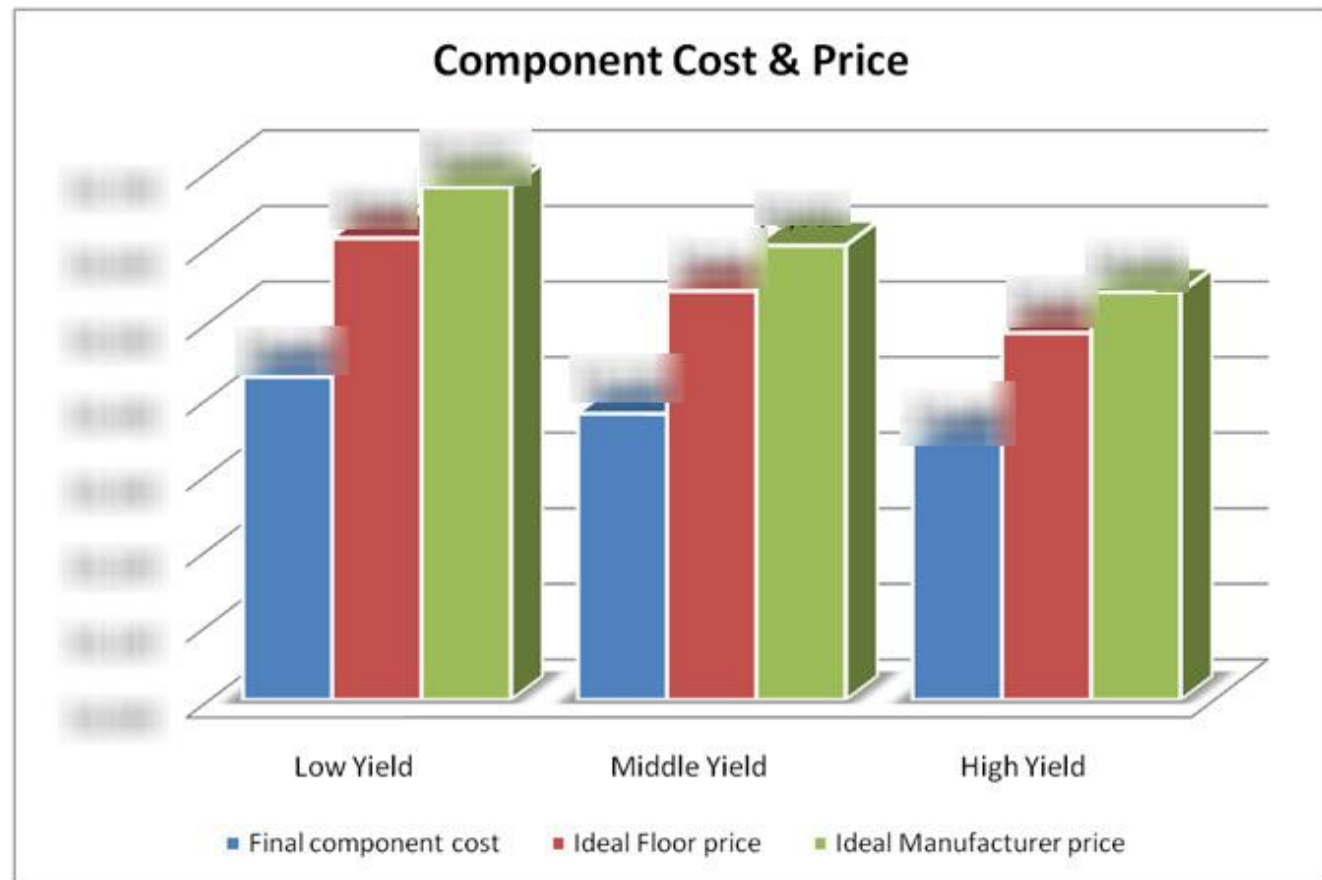
| Packaging Process Step | Cost | Breakdown |
|------------------------|------|-----------|
| Package Element | | |
| Dies Bonding | | |
| Curing | | |
| Phosphore Coating | | |
| Silicone overmolded | | |
| TOTAL | | |

- The total packaging cost is estimated to \$0.XXX
- The cost by step includes the equipment cost, the material cost and the labour cost.



| Versions | Final component cost | Ideal Floor price | Ideal Manufacturer price |
|--------------|----------------------|-------------------|--------------------------|
| Low Yield | 1000 | 1500 | 2000 |
| Middle Yield | 1200 | 1800 | 2400 |
| High Yield | 1400 | 2100 | 2800 |

The ideal manufacturer price is obtained for a binning yield of 100%.



- Reverse costing analysis represents the best cost/price evaluation given the publically available data, completed with industry expert estimates.
- These results are open for discussion. We can re-evaluate this circuit with your information. Please contact us:

A contact information card for SYSTEMPlus CONSULTING. The card is white with a blue circular graphic on the right side that contains a stylized map of Europe with the word "Nantes" and a dot indicating the location. The card includes the company logo, address, phone and fax numbers, and email and website information.

The logo for SYSTEMPlus CONSULTING, featuring a stylized globe icon to the left of the text "SYSTEMPlus" in blue and "CONSULTING" in red below it.

Address :
9 rue Alfred Kastler
BP 10748
F-44307 Nantes Cedex 3
FRANCE

Phone +33 240 180 916
Fax +33 253 551 059

info@systemplus.fr
www.systemplus.fr